Unitized Semiconductor Devices - Page 1 of 1



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Inclosure Material:	
Metal	
Overall Length:	
0.260 inches	
Terminal Length:	
0.500 inches	
Overall Diameter:	
0.370 inches	
Joint Electronic Device E	ngineering Council/jedec/case Outline Designation:
To-71	
Component Name And Q	uantity:
2 transistor	
Mounting Method:	
Terminal	
Terminal Circle Diameter	:
0.100 inches	
Features Provided:	
Hermetically sealed case	
Semiconductor Material:	
Silicon all transistor	
Voltage Rating In Volts P	er Characteristic:
45.0 breakdown voltage,	collector-to-base, emitter open all transistor and 45.0 breakdown voltage, collector-to-emitter, base open all
ransistor and 6.0 emitter t	o base voltage, static, collector open all transistor
Current Rating Per Chara	icteristic:
30.00 milliamperes source	cutoff current all transistor
Power Rating Per Charac	teristic:
250.0 milliwatts small-signa	al input power, common-collector preset all transistor
Transfer Ratio:	
60.0 small-signal short-cire	cuit forward current transfer ratio, common-emitter all transistor
Maximum Operating Tem	purature Per Measurement Point:
200.0 degrees celsius amb	ient air
Special Features:	
Internal junction configurat	on transistor npn
Terminal Type And Quan	tity:
8 uninsulated wire lead	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	
A110a0	